

60V NPN MEDIUM POWER TRANSISTOR IN SOT223

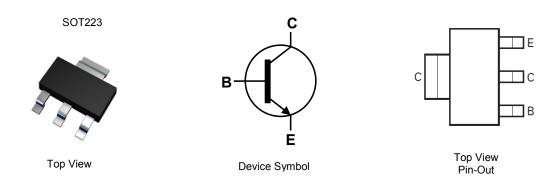
Features

- BV_{CEO} > 60V
- I_C = 6A High Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 100mV @ 1A
- R_{CE(sat)} = 44mΩ for a Low Equivalent On-Resistance
- h_{FE} Specified Up to 10A for a High Gain Hold Up
- Complementary PNP Type: FZT951
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The FZT851Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT223 Type DN
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208@3
- Weight: 0.112 grams (Approximate)



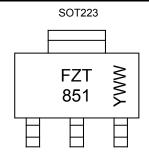
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT851TA	AEC-Q101	FZT851	7	12	1000
FZT851QTA	Automotive	FZT851	7	12	1000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



FZT 851 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 0= 2020) WW or $\overline{W}W$ = Week Code (01–53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	6	Α
Peak Pulse Current	Ісм	20	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	0	3.0 24	W	
Linear Derating Factor	(Note 6)	- P _D	1.6 12.8	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 7)		$R_{\theta JL}$	8.8		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

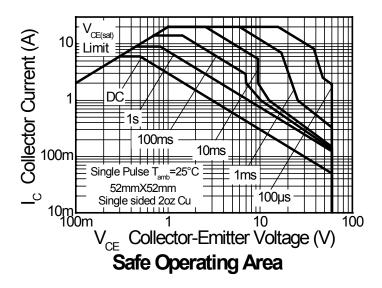
^{6.} Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

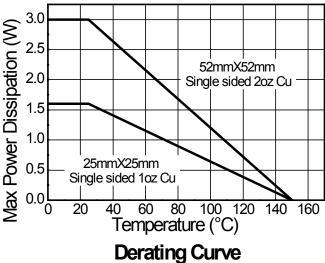
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

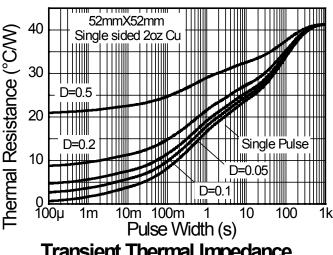
^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.

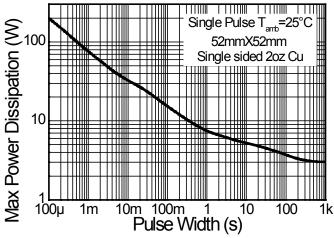


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



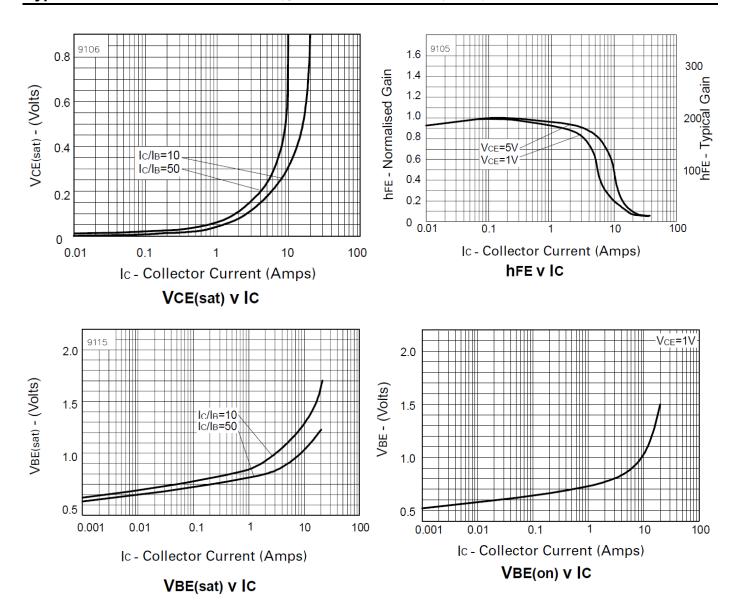
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	220	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	150	220	_	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	85	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	_	<1 -	50 1	nΑ μΑ	V _{CB} = 120V V _{CB} = 120V, T _A = +100°C
Collector Cut-Off Current	I _{CER}	_	<1 —	50 1	nΑ μΑ	V_{CE} = 120V, $R_B \le 1kΩ$ V_{CE} = 120V, T_A = +100°C
Emitter Cut-Off Current	I _{EBO}	_	<1	10	nA	V _{EB} = 6V
		100	200	_	_	I _C = 10mA, V _{CE} = 1V
DC Current Coin (Note 0)		100	200	300		I _C = 2A, V _{CE} = 1V
DC Current Gain (Note 9)	h _{FE}	75	120	_		I _C = 5A, V _{CE} = 1V
		25	50	_		I _C = 10A, V _{CE} = 1V
		_	_	50	mV	I _C = 100mA, I _B = 5mA
Callegtor Emitter Saturation Valtage (Note 0)	V	_	_	100		I _C = 1A, I _B = 50mA
Collector-Emitter Saturation Voltage (Note 9)	V _{CE} (sat)	_	_	170		I _C = 2A, I _B = 50mA
		_	_	375		I _C = 6A, I _B = 300mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	1,200	mV	I _C = 6A, I _B = 300mA
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	_	_	1,150	mV	I _C = 6A, V _{CE} = 1V
Current Gain-Bandwidth Product (Note 9)	f _t	_	130	_	MHz	I _C = 100mA, V _{CE} = 10V, f = 50MHz
Output Capacitance	C_obo	_	45	_	pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{on}	_	45	_	ns	$I_C = 1A$, $V_{CC} = 10V$,
Switching Times	t_{off}	_	1,100	_	115	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

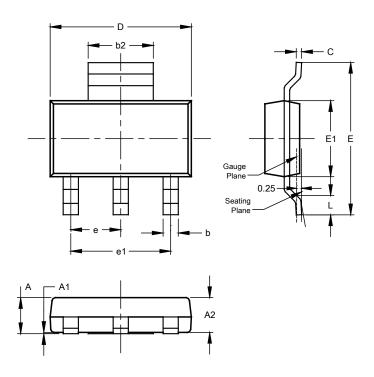




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

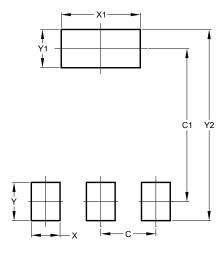


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15	-		
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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